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STMicroelectronics BU508AW

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# **BU508AW**

# High voltage NPN power transistor for standard definition CRT display

### **Features**

- State-of-the-art technology:
  - Diffused collector "Enhanced generation"
- Stable performances versus operating temperature variation
- Low base-drive requirement
- Tight h<sub>FF</sub> range at operating collector current
- High ruggedness
- TO-247 semi-insulated power package

## **Applications**

- Horizontal deflection output for CRT TV
- Switch mode power supplies for CRT TV

# **Description**

The BU508AW is manufactured using diffused collector in planar technology adopting new and enhanced high voltage structure for updated performance to the horizontal deflection stage.

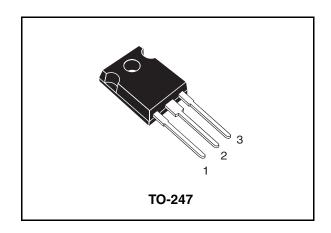


Figure 1. Internal schematic diagram

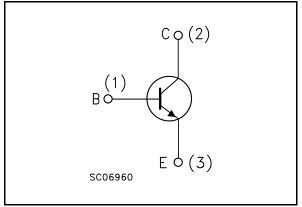


Table 1. Device summary

Order code	Marking	Package	Packaging
BU508AW	BU508AW	TO-247	Tube

August 2007 Rev 2 1/11



Content BU508AW

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BU508AW Electrical ratings

# 1 Electrical ratings

Table 2. Absolute maximum rating

Symbol	Parameter	Value	Unit
V <sub>CES</sub>	Collector-emitter voltage (V <sub>BE</sub> = 0)	1500	V
V <sub>CEO</sub>	Collector-emitter voltage (I <sub>B</sub> = 0)	700	V
V <sub>EBO</sub>	Collector-base voltage (I <sub>C</sub> = 0)	9	V
I <sub>C</sub>	Collector current	8	Α
I <sub>CM</sub>	Collector peak current (t <sub>P</sub> < 5ms)	15	Α
I <sub>B</sub>	Base current	4	Α
P <sub>TOT</sub>	Total dissipation at T <sub>c</sub> = 25°C	125	W
T <sub>stg</sub>	Storage temperature	-65 to 150	°C
TJ	Max. operating junction temperature	150	

#### Table 3. Thermal data

Symbol	Parameter	Value	Unit
R <sub>thj-case</sub>	Thermal resistance junction-case max	1	°C/W



**Electrical characteristics** 

BU508AW

## 2 Electrical characteristics

 $(T_{case} = 25^{\circ}C \text{ unless otherwise specified})$ 

Table 4. Electrical characteristics

Symbol	Parameter	Test conditions		Тур.	Max.	Unit
I <sub>CES</sub>	Collector cut-off current (V <sub>BE</sub> =0)	V <sub>CE</sub> = 1500V V <sub>CE</sub> = 1500V; T <sub>C</sub> = 125°C			0.2 2	mA mA
I <sub>EBO</sub>	Emitter cut-off current (I <sub>C</sub> =0)	V <sub>EB</sub> = 9V			1	mA
V <sub>CEO(sus)</sub> (1)	Collector-emitter sustaining voltage (I <sub>C</sub> =0)	I <sub>C</sub> = 100mA	700			٧
V <sub>CE(sat)</sub> (1)	Collector-emitter saturation voltage	$I_C = 4.5A$ $I_B = 1.6A$			1	٧
V <sub>BE(sat)</sub> (1)	Base-emitter saturation voltage	$I_{C} = 4.5A$ $I_{B} = 2A$			1.1	٧
h <sub>FE</sub> <sup>(1)</sup>	DC current gain	$I_C = 0.1A$ $V_{CE} = 5V$ $I_C = 4.5A$ $V_{CE} = 5V$			30	
t <sub>s</sub>	Inductive load Storage time Fall time	$\begin{split} I_C &= 4.5 \text{A} & I_{B(on)} = 0.5 \text{A} \\ V_{BE(off)} &= -2.7 \text{V} & f_h = 16 \text{KHz} \\ L_{BB(off)} &= 4.5 \mu \text{H} \end{split}$		2.5 0.2		μs μs

<sup>1.</sup> Pulsed: Pulse duration = 300 ms, duty cycle 1.5 %



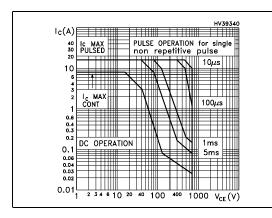
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**Electrical characteristics** 

## 2.1 Electrical characteristics (curves)

Figure 2. Safe operating area

Figure 3. Derating curve



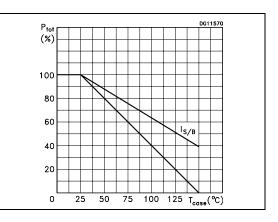
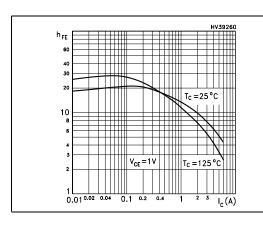


Figure 4. DC current gain

Figure 5. DC current gain



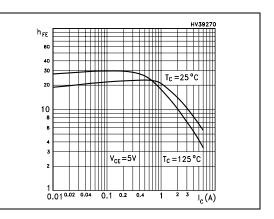
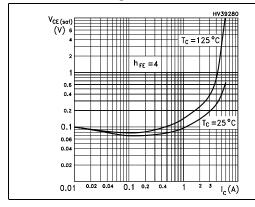
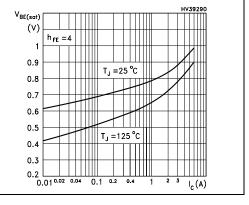


Figure 6. Collector-emitter saturation voltage

Figure 7. Base-emitter saturation voltage



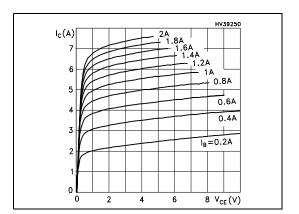




**Electrical characteristics** 

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Figure 8. Output characteristics



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**Electrical characteristics** 

#### 2.2 **Test circuits**

Figure 9. Power losses and inductive load switching

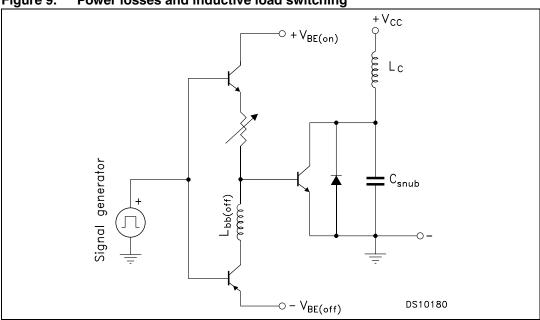
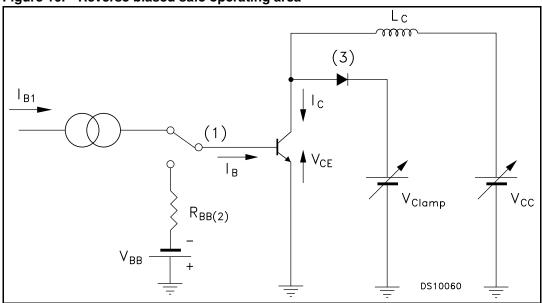


Figure 10. Reverse biased safe operating area







Package mechanical data

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#### 3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com



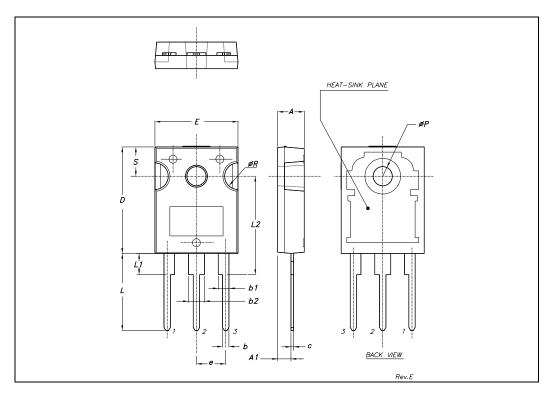
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#### BU508AW

#### Package mechanical data

#### **TO-247 MECHANICAL DATA**

DIM		mm.			inch		
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
Α	4.85		5.15	0.19		0.20	
A1	2.20		2.60	0.086		0.102	
b	1.0		1.40	0.039		0.055	
b1	2.0		2.40	0.079		0.094	
b2	3.0		3.40	0.118		0.134	
С	0.40		0.80	0.015		0.03	
D	19.85		20.15	0.781		0.793	
E	15.45		15.75	0.608		0.620	
е		5.45			0.214		
L	14.20		14.80	0.560		0.582	
L1	3.70		4.30	0.14		0.17	
L2		18.50			0.728		
øΡ	3.55		3.65	0.140		0.143	
øR	4.50		5.50	0.177		0.216	
S		5.50			0.216		





Revision history BU508AW

# 4 Revision history

Table 5. Document revision history

Date	Revision	Changes
02-Mar-2007	1	Initial release.
14-Aug-2007 2		Complete document, added all curves (2.1: Electrical characteristics (curves)





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